PRODUCT SPECIFICATION

Model No: CSM-57211E/CSM-57221E

Descriptions:

- 2.0Inch Dot-Matrix Display
- 5*7 Array with X-Y Select.
- CSM-57211: Column Anode, Row Cathode
- CSM-57221: Column Cathode, Row Anode
- Emitting Color: Orange









CUSTOMER APPROVED SIGNATURES	APPROVED BY	CHECKED BY	PREPARED BY

CHINA SEMICONDUCTOR CORPORATION

Address:2FL. NO.909,Chung-Cheng Road, Chung-Ho City Taipei Hsien,Taiwan.

Tel:886-2-2223-9696 Fax:886-2-2223-9377

OPTO PLUS TECHNOLOGIES CO.,LTD

Address:696 Shun jiang Rd.,Ji Shan St.Shaoxing, ZheJiang,China

Tel:86-0575-88623888 Fax:86-0575-88623112

Spec. No.	PS-ND-0710
Rev.	Α

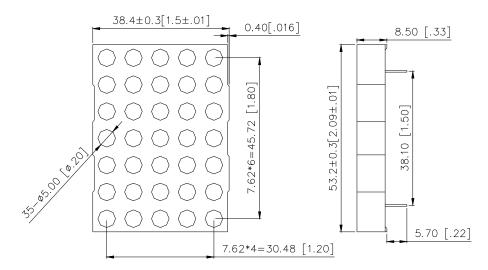
Features -

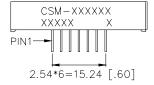
- 1. 2.0 inch (50.7mm) Matrix height.
- 2. Case mold type.
- 3. RoHs compliant.
- 4. Low power consumption.
- 5. Easy mounting on P.C. board or socket.

■ Device Selection Guide -

Part No.	C	hip	Description		
Part No.	Material	Emitted Color	Column	Row	
CSM-57211E	GaAsP	Orongo	Anode	Cathode	
CSM-57221E	GaASP	Orange	Cathode	Anode	

Package Dimensions -





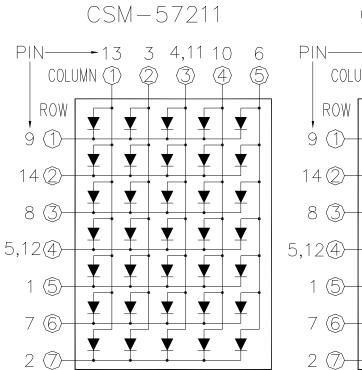
NOTE:

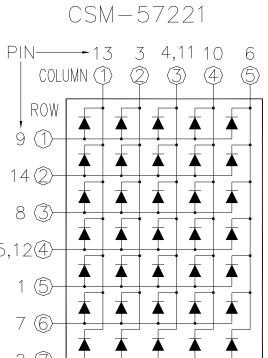
- 1 All pins are Ø0.5(.02).
- 2 All dimensions are in millimeters (inch), tolerance is ± 0.25 (.01) unless otherwise noted.

Page:

Spec. No.	PS-ND-0710
Rev.	Α

■ Internal Circuit Diagrams -





CSM-57211		CSM-57221					
PIN NO.	FUNCTION	PIN NO.	FUNCTION	PIN NO.	FUNCTION	PIN NO.	FUNCTION
1	Cathode Row 5	8	Cathode Row 3	1	Anode Row 5	8	Anode Row 3
2	Cathode Row 7	9	Cathode Row 1	2	Anode Row 7	9	Anode Row 1
3	Anode Column 2	10	Anode Column 4	3	Cathode Column 2	10	Cathode Column 4
4	Anode Column 3	11	Anode Column 3	4	Cathode Column 3	11	Cathode Column 3
5	Cathode Row 4	12	Cathode Row 4	5	Anode Row 4	12	Anode Row 4
6	Anode Column 5	13	Anode Column 1	6	Cathode Column 5	13	Cathode Column 1
7	Cathode Row 6	14	Cathode Row 2	7	Anode Row 6	14	Anode Row 2

Page:

Spec. No.	PS-ND-0710
Rev.	Α

■ Absolute Maximum Rating -

(Ta=25°C)

			(1a-25 C	
Parameter	Symbol	Rating	Unit	
Power Dissipation Per Dice	Pad	70	mW	
Continuous Forward Current Per Dice	laf	25	mA	
Peak Current Per Dice(duty cycle 1/10, 1kHz)	IPF	90	mA	
Derating Linear From 25℃ Per Dice	-	0.33	m A /℃	
Reverse Voltage Per Dice	V R	5	٧	
Operating Temp.	Topr	-35 ~ +85	$^{\circ}\!\mathbb{C}$	
Storage Temp.	Tstg	-35 ~ +85	$^{\circ}\!\mathbb{C}$	
Solder temperature 1/16 inch below seating plane for 3 seconds at 260 $^{\circ}\mathrm{C}$				

■ Electro-optical Characteristics -

(Ta=25°ℂ)

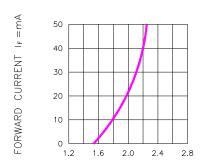
Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Forward Voltage Per Segment	VF	-	2.1	2.8	V	IF=20mA
Luminous Intensity Per Segment	lv	ı	6500	-	ucd	IF=10mA
Peak Emission Wavelength	λp	-	632	-	nm	IF=20mA
Dominant Wavelength	λd	-	624	-	nm	IF=20mA
Spectrum Radiation Bandwidth	Δλ	-	35	-	nm	IF=20mA
Reverse Current	IR	-	-	100	μ A	VR=5V
Luminous Intensity Matching Ratio	IV-m	-	-	2:1	-	lp=80mA 1/16Duty

Page:

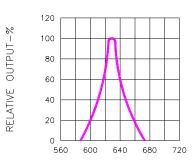
Spec. No.	PS-ND-0710
Rev.	Α

■ Typical Electrical / Optical Charateristics Curves -

(Ta = 25[°]C Unless Otherwise Noted)



FORWARD VOLTAGE (V_F) -VOLTS Fig.1 FORWARD CURRENT VS. FORWARD VOLTAGE



WAVELENGTH (λ) -nm Fig.2 SPECTRAL RESPONSE

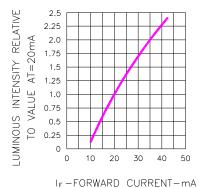
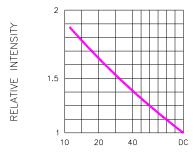


Fig.3 RELATIVE LUMINOUS INTENSITY VS. FORWARD CURRENT



DUTY CYCLE % PER SEGMENT (AVERAGE $I_F = 10 \text{mA}$)
Fig.5 LUMINOUS INTENSITY VS. DUTY CYCLE

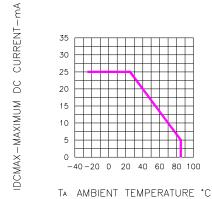


Fig.4 MAXIMUM ALLOWABLE DC CURRENT PER SEGMENT VS. A FUNCTION OF AMBIENT TEMPERATURE

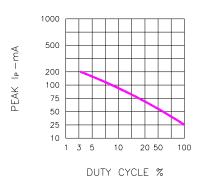
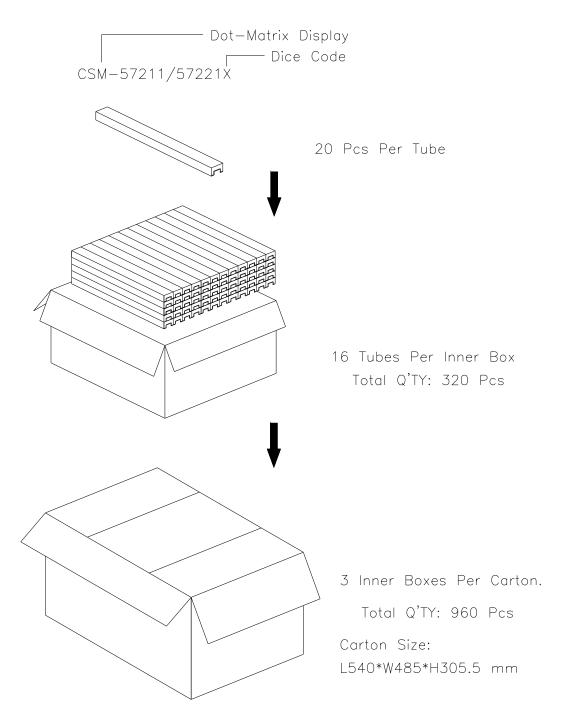


Fig.6 MAX PEAK CURRENT VS. DUTY CYCLE % (REFRESH RATE f=1 KHz)

Spec. No.	PS-ND-0710
Rev.	Α

Package Dimensions



Note: The specifications are subject to change without notice. Please contact us for updated information.